Effect of silcate melt composition and fO₂ on metal-silicate partitioning of Si, Nb, Ta and V

N. RAI, M.J. WALTER, AND C.J. HAWKESWORTH

Dept. of Earth Sciences, University of Bristol, U.K. BS81RJ; glxnr@bris.ac.uk

High pressure experiments indicate that Nb and V have very similar metal-silicate partition coefficients and are slightly siderophile at reducing conditions [1]. It is postulated that the upper mantle depletion in V, and the depletion in Nb relative to Ta in mantle reservoirs, could be due to sequestering of V and Nb into the core [1]. Further, the mantle abundance of V together with high P-T partitioning data help to constrain the conditions of core segregation [2]. Nb, V and Ta can exist in variable and high oxidation states. As such, their partitioning behaviour is dependent on oxygen fugacity, and by way of analogy with other high-valence cations(Mo⁶⁺, W^{4+,6+}), partitioning may also be sensitive to silicate melt composition [3]. Here we report new experimental results on the effects of silicate melt composition and oxygen fugacity on the partitioning behaviour of these elements along with Si. Experiments were made at 2 GPa and 2000 K and over a range of relative oxygen fugacities from ~IW-3 to IW-6. Silicate melts range from basaltic to peridotitic in composition. The melt compositional parameter, NBO/T, is used as a proxy for silicate melt composition, and has values from 0.7 to 4. Isobaric, isothermal data for each element were regressed using the equation: $\ln D^{\text{met/sil}} = a + bfO_2 + c(nbo/T)$. Regressions show that at the experimental conditions both Nb and V exist in 3+ valence states, Si exists in +4 state whereas Ta likely exists in a 5+ valence state. In contrast, higher pressure (25 GPa) partitioning data [1] show a 5+ valence state for Nb, which may imply a possible change in valence as the absolute fO2 of the IW buffer becomes more oxidizing with pressure. Documenting such changes in valence is critical for parameterizations that rely on exchange partition coefficients [2]. Regressions indicate that melt composition has little effect on the partitioning behaviour of V, Nb and Ta although Si shows strong compositional dependency. For trivalent Nb and V this is generally consistent with findings that melt composition has a small effect on partitioning of lower valence elements such as Ni^{2+} and Co^{2+} [4]. A higher valence state of 5+ for Nb at higher pressures implies a greater effect of melt composition on partitioning. However, we find that Ta^{5+} shows virtually no compositional dependence, in marked contrast to Si^{4+} , and also that Ta^{5+} becomes siderophile at less reduced conditions than Si⁴⁺.

References

[1] Wade et al. (2001), *Nature* **409**, 75-78. [2] Wade & Wood (2005), *EPSL* **236**, 78-95. [3] Walter et al. (1995), *Science* **270**,1186-1189. [4] Jaeger & Drake (2000) *GCA* **64**, 3887-3895.